Erratum to: Ultrathin flexible InGaZnO transistor for implementing multiple functions with a very small circuit footprint

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The article “Ultrathin flexible InGaZnO transistor for implementing multiple functions with a very small circuit footprint” written by Chaoqi Dai, Peiqin Chen, Shaocheng Qi, Yongbin Hu, Zhitang Song, and Mingzhi Dai, was erroneously originally published electronically on the publisher’s internet portal (currently SpringerLink) on 30 September 2020 with caption of Fig. 1 and related context, and the Acknowledgements.

Instead of

Figure 1 (d) To implement an AND gate, the traditional design uses 3 transistors, the latest report uses 2 transistors [14], and the single transistor design uses 1 transistor.

It should read

Figure 1 (d) To implement an NAND gate, the traditional design uses 3 transistors, the latest report uses 2 transistors [14], and the single transistor design uses 1 transistor.

On page 2, instead of

As illustrated in Fig. 1(d), the conventional design of the AND logic gate has 3 transistors, whereas a recently-published design has two transistors [14]. The design here can implement the AND gate using only one transistor.

It should read

As illustrated in Fig. 1(d), the conventional design of the NAND logic gate has 3 transistors, whereas a recently-published design has two transistors [14]. The design here can implement the logic gates such as logic NAND gate or logic AND gate using only one transistor.

In the Acknowledgements, instead of

Acknowledgements

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It should read

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